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UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT(S) Matthias Passlack GROUP ART UNIT: 2812
APPLN. NO.: 10/051,494 EXAMINER: Unassigned
FILED: January 18, 2002
TITLE: ARTICLE COMPRISING AN OXIDE LAYER ON A GaAs-BASED
SEMICONDUCTOR STRUCTURE AND METHOD OF FORMING
SAME

Certificate of Mailing

Date of deposit: May 29, 2002

I hereby certify that this paper is being deposited with the United States Postal Service on the date indicated above, as first-class mail, with sufficient postage attached thereto, in an envelope addressed to the Assistant Commissioner for Patents, Washington, D.C.


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PRELIMINARY AMENDMENT

Assistant Commissioner of Patents
Washington, D.C. 20231

Sir:

Please enter this Preliminary Amendment in the above-entitled application.

Please enter the following amendments:

IN THE SPECIFICATION:

On page 1, line 5, please insert the following new heading and paragraph:

Government Rights

a'
This invention was made with Government support under Subcontract/Purchase Order No. 025307 awarded by the University of Southern California (Prime Contract MDA904-93-C-L042). The Government has certain rights in this invention."